

# Carbon substitution effect in $\text{MgB}_2$

Jai Seok Ahn<sup>1,†</sup> and Eun Jip Choi<sup>1,2,‡</sup>

<sup>1</sup>Center for Strongly Correlated Materials Research, Seoul National University, Seoul 151-742, Korea

<sup>2</sup>Department of Physics, University of Seoul, Seoul 130-743, Korea

(October 30, 2018)

We investigated carbon substitution effect on boron plane of superconducting  $\text{MgB}_2$ .  $\text{MgB}_2$  and  $\text{MgB}_{1.8}\text{C}_{0.2}$  samples are synthesized under high pressure furnace.  $\text{MgB}_{1.8}\text{C}_{0.2}$  are characterized as  $\text{AlB}_2$ -type single phase with smaller B-B distance. During the superconducting transition, two distinct onset temperatures are observed in  $\text{MgB}_{1.8}\text{C}_{0.2}$ .

Since the discovery of superconducting property in  $\text{MgB}_2$  by Akimitsu *et al.* [1], much efforts are spent on understanding the type of carriers and the way of optimization with chemical substitution. As far as we know, chemical substitution of elements are focused mostly on Mg-site surrounded by neighboring 12 boron cages, with an exception of  $^{10}\text{B}$  isotope effect by Bud'ko *et al.* [2]. Several alkali and alkali earth and group III elements are thoroughly tested, such as Al [3], Be [4], and Li [5], however, decrease of transition temperature is observed in all cases, partly due to the structural instability introduced by ion size difference between Mg and substituting elements. If the structural uniqueness is essential in finding superconducting borides, possibility may be low to find superconductivity among the existing diboride compounds containing heavy elements as suggested by structural analysis [6].

With these in mind, we focused on the chemical substitution on boron plane itself, which carries superconducting property. On the crystallographic point of view, boron shares similarity in structure with  $\text{B}_4\text{C}$ , C(graphite), and BN in its rhombohedral phase and may be substituted with those similar materials with high melting points. In this paper, we will report our result on the carbon substitution effect on boron site of  $\text{MgB}_2$ .

$\text{MgB}_2$  and  $\text{MgB}_{1.8}\text{C}_{0.2}$  samples are synthesized with high pressure furnace. Starting materials are powders of Mg (99.8%, Alfa), amorphous B (99.99%, Alfa), and carbon (high purity activated charcoal, Wako). Stoichiometric amounts of powders are weighed, thoroughly mixed in an agate mortar, and pressed into pellets. The pellets are placed in a tungsten vessel with a close-fitting cap, reacted one hour at 850 °C, and subsequently annealed at 500 °C for 12 hours under 20 atm of high purity argon atmosphere. Some amounts of magnesium turnings (99.9%, Acros) are used as getters inside the furnace.

Figure 1(a) show x-ray  $\theta$ - $2\theta$  diffraction patterns of  $\text{MgB}_2$  and  $\text{MgB}_{1.8}\text{C}_{0.2}$  measured with Cu  $K_\alpha$  source with  $2\theta$  step of  $0.05^\circ$ . In both patterns, single group of  $\text{AlB}_2$ -type reflections and small amounts of MgO impurities (shown with asterisks) are observed and any other im-

purities of B, C, or Mg is not observed within accuracy. Our calculation of hexagonal cell parameters for  $\text{MgB}_2$ ,  $a_H = 3.083 \text{ \AA}$  and  $c_H = 3.520 \text{ \AA}$  is quite close to reported one: 3.086 and 3.524  $\text{\AA}$ . (Here, peak positions of MgO are used as internal standards.) Parameters are also calculated for  $\text{MgB}_{1.8}\text{C}_{0.2}$ :  $a_H = 3.070 \text{ \AA}$  and  $c_H = 3.520 \text{ \AA}$ . From these results, we notice that only  $a_H$  (B-B distance) decreases and  $c_H$  (separation between B planes) is not varied with carbon substitution. This is more clear from Fig. 1(b), showing the movement of (100), (101), and (002) lines with carbon substitution.

Comparison with the result of other elements is intriguing at this point. In  $\text{Al}^{3+}$ -substitution (hole doping), both  $a$ - and  $c$ -axis length decrease with doping, and the change in  $c$ -axis is significant at high doping limits ( $\geq 0.25 \text{ Al}$ ) [3]. For  $\text{Be}^{2+}$ -substitution (no doping, ion size effect), it is well-known that Be cannot dope Mg site because it forms stable phase of  $\text{BeB}_2$  [7,4]. And in  $\text{Li}^+$ -substitution (electron doping),  $c$ -axis does not vary and  $a$ -axis length decreases with doping concentration ( $\leq 0.3 \text{ Li}$ ) [5], quite similar to our result:  $\text{C}^{4+}$  ion is smaller than  $\text{B}^{3+}$  [8] and electron doping is expected from ionic picture.

In order to see the changes in superconducting properties, dc resistivity is measured on a closed-cycle He refrigerator (Janis, CCS350), with a standard four-point probe technique with polished rectangular sample of dimension  $\sim 2 \times 5 \times 1 \text{ mm}^3$ , where electrical contact is made with silver epoxy (Dotite) and thermal one with grease (Apiezon, N). Figure 2 shows the sample resistivities normalized with the values at 50 K and inset shows the region of phase transition. Normal state resistivity level of  $\text{MgB}_2$  and  $\text{MgB}_{1.8}\text{C}_{0.2}$  is different by two orders of magnitude, such as  $\rho(50\text{K}) = 93 \mu\Omega\text{cm}$  ( $\text{MgB}_2$ ) and  $19 \text{ m}\Omega\text{cm}$  ( $\text{MgB}_{1.8}\text{C}_{0.2}$ ), partly due to the low density of our  $\text{MgB}_{1.8}\text{C}_{0.2}$  pellet. However, their normal state power-law dependence ( $\rho \sim a + bT^2$ ) and residual resistivity ratio ( $\rho(T_C^+)/\rho(300\text{K}) \sim 0.55$ ) are quite similar. In  $\text{MgB}_2$ , the resistivity drops at 38.8 K and the transition is completed within 1 K, as shown in the inset, which is quite close to the report of Akimitsu *et al.* [1]

Compared with  $\text{MgB}_2$ , the transition width is very broad ( $\sim 8$  K) in  $\text{MgB}_{1.8}\text{C}_{0.2}$ , which begins at 41 K and ends at 33 K. Also, the resistivity shows two distinct onset temperatures indicated with  $\nabla$  symbols in the inset ( $T_{c1} \sim 41$  K and  $T_{c2} \sim 37$  K). Considering the single group of  $\text{AlB}_2$ -type patterns of x-ray, structural inhomogeneity may not be related with this observation, however, some intergrain effect should be counted. According to our preliminary results of different doping concentrations, structural segregation begins at some higher doping and  $\text{MgB}_{1.8}\text{C}_{0.2}$  is near optimum in its property. Because carbon substitution gives influences in effective mass and charge valency of undoped boron planes, we speculate some changes in phonon or electronic structure corresponding to this carbon substitution. In this respect, further progresses with boron plane substitution are anticipated.

This work was supported by KRF-99-041-D00185 and by the KOSEF through the CSCMR. We acknowledge the help of J. H. Bae, Y. J. Kim, and S. C. Kim of Univ. of Seoul.

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<sup>†</sup> jsahn@physics.uos.ac.kr

<sup>‡</sup> echoi@uoscc.uos.ac.kr

- [1] J. Nagamatsu, N. Nakagawa, T. Muranaka, Y. Zenitani, and J. Akimitsu, *Nature* **410**, 63 (2001).
- [2] S. L. Bud'ko, G. Lapertot, C. Petrovic, C. E. Cunningham, N. Anderson, and P. C. Canfield, *cond-mat/0101463* (2001).
- [3] J. S. Slusky, N. Rogado, K. A. Regan, M. A. Hayward, P. Khalifah, T. He, K. Inumaru, S. Loureiro, M. K. Haas, H. W. Zandbergen and R. J. Cava, *cond-mat/0102262* (2001).
- [4] Israel Felner, *cond-mat/0102508* (2001).
- [5] Y. G. Zhao, X. P. Zhang, P. T. Qiao, H. T. Zhang, S. L. Jia, B. S. Cao, M. H. Zhu, Z. H. Han, X. L. Wang, and B. L. Gu, *cond-mat/0103077* (2001).
- [6] A. Bianconi, N. L. Saini, D. Di Castro, S. Agrestini, G. Campi, A. Sacconne, S. De. Negri, M. Giovanni, and M. Colapietro, *cond-mat/0102410* (2001).
- [7] C. L. Hoenig, C. F. Cline, and D. E. Sands, *J. Am. Cer. Soc.* **44**, 385 (1961).
- [8] R. D. Shannon, *Acta Cryst. A* **32**, 751 (1976).

FIG. 1. (a) X-ray  $\theta$ - $2\theta$  diffraction patterns( $\text{Cu K}\alpha$ ) of  $\text{MgB}_2$  and  $\text{MgB}_{1.8}\text{C}_{0.2}$  powders. (b) Enlarged patterns in the region of the (100), (101), and (002) reflections.  $\text{MgO}$  impurities are shown with asterisks.

FIG. 2. Dc resistivities normalized at 50 K ( $\rho(T)/\rho(50\text{K})$ ) of  $\text{MgB}_2$  and  $\text{MgB}_{1.8}\text{C}_{0.2}$ . Inset shows the region of the transition temperatures.

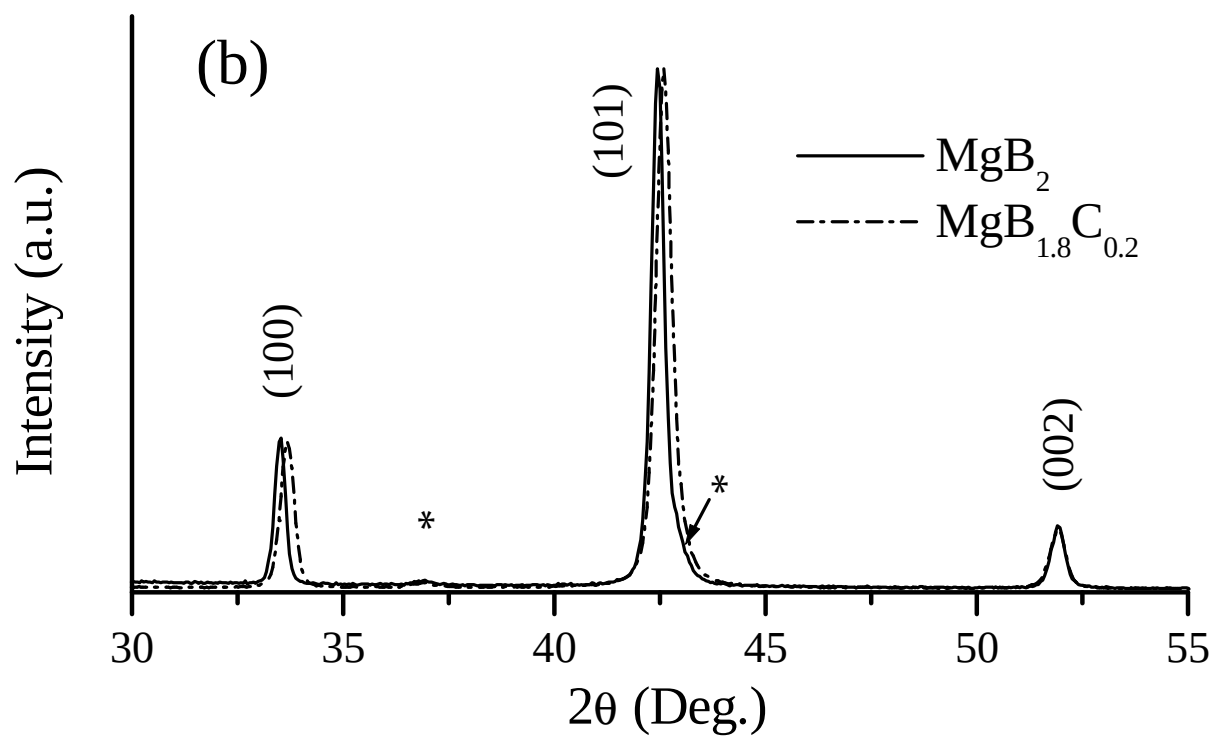
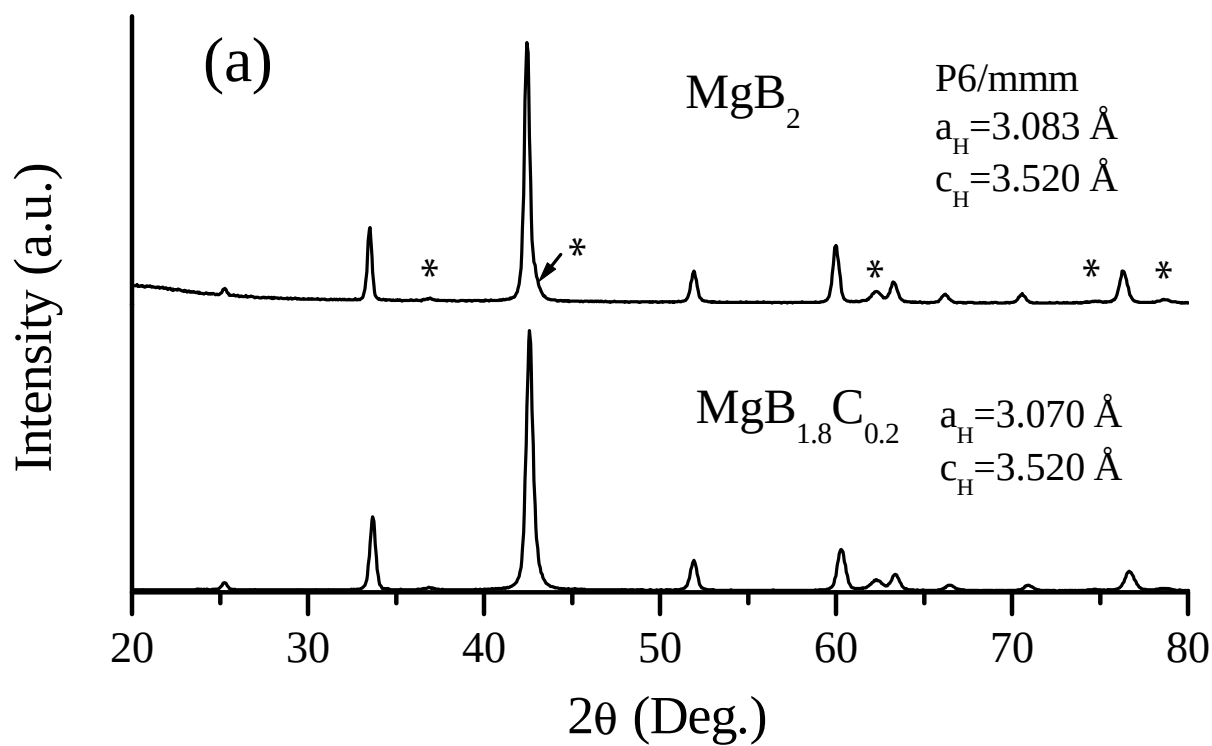


Fig. 1 of Ahn and Choi

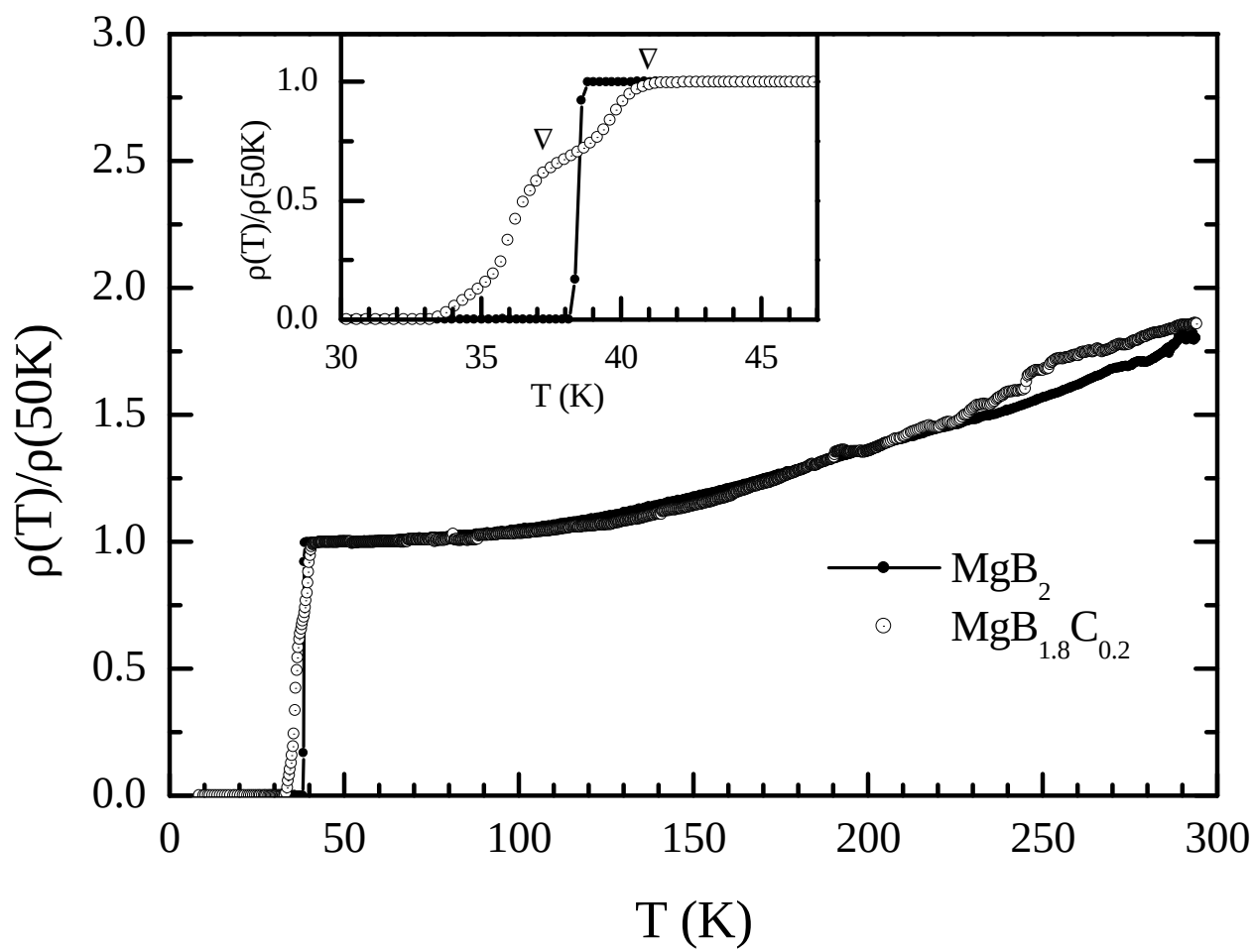


Fig. 2 of Ahn and Choi